The Electromagnetic Properties of the Generalized Cantor Stack in Spherical Multilayered Systems

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Abstract—By the transfer matrix approach we numerically study the electromagnetic properties (narrow peak positions) of the transmission spectra for microspheres coated by a multilayered stack with the generalized Cantor structure (fractal). As opposed to the standard Cantor system with removed \( \gamma/3 \) \( [\gamma = 1] \) section we consider here the solid stack with Si/SiO\(_2\) layers at general \( \gamma \) value. In such a solid composition the SiO\(_2\) layers replace the empty Cantor sections and the parameter \( \gamma \) acquires meaning of a specific control parameter. At successive generations the central layers (in blocks of the spherical stack) acquire a progressive decreased width that leads to generation of the radially inhomogeneous defects. We show that the wave phase interference in such a fractal pattern leads to formation of very narrow electromagnetic transmittance resonances that can be used in modern optoelectronics.

1. INTRODUCTION

It is well known that except for the whispering gallery mode (WGM) regime [1, 2], a bare dielectric sphere has a complex spectrum electromagnetic low quality (\( Q \) factor) eigenoscillations because of the energy leakage into the outer space [3]. The case of the compound structure, when the dielectric sphere is coated by an alternative stack, is much richer. The \( Q \)-factor of optical oscillations has a large value in the frequency regions of weak transmission, and beyond these regions, \( Q \) remains small [4–13]. In this paper we numerically analyze the wave phase interference in a Cantor generalized fractal pattern in the spherical stack. To do that we explore the transmission spectra and frequency resonances of such structures deposited on surface of a dielectric microsphere.

2. THE GENERALIZED CANTOR SET

The well known Cantor set is created by repeatedly deleting the open central third of a set of line segments. One can construct various generalizations of the set by, say, cutting the segments into a different number of intervals or choosing another scaling factor (see, e.g., [14, 15]). In this paper, we construct a Cantor stack by repeatedly replacing (not deleting) of the central third of a set of stack by layer of material. The generalized Cantor set in radial direction can be constructed from a homogeneous stack by following iterations.

The zero-order iteration (initiator) is the homogeneous spherical stack deposed on the surface of the bare microsphere \( A \) (see Fig. 1) with radius \( r_1 \). A layer of the stack has width \( d \), which is separated (as \( 2B + C \)) in two symmetric periphery fragments \( (B) \) with length \( pd \) and one central fragment \( (C) \) with length \( \gamma pd \) respectively (\( \gamma \) is a free parameter), such that for \( 2B + C \) system the length is \( pd + \gamma pd + pd = d \). From the latter we obtain \( p = 1/(2 + \gamma) \). If \( \gamma = 1 \) such case is simplified to the standard Cantor set. In this paper, we apply such idea as follows. We generate in 1-st iteration (1st...
Figure 1. The structure of the multilayered microsphere coated by a Cantor stack with order $R_3$ (15 layers). $A$ is a bottom glass microsphere ($n = 1.5$) with radius $r_1$, $B$ is Si layer ($n = 3.58$), $C$ is SiO$_2$ ($n = 1.46$) layer, $D$ is surrounding space. Typically $r_1 \sim 1 \mu m$, the width of layers dependently on the position in a Cantor stack is $d \sim (1.3 \div 0.06) \mu m$.

with order $R_1$) the stack as $B_1 + C_1 + B_1$ (3 layers in the stack, $R_1$ order). In 2-nd iteration we have $(B_2 + C_2 + B_2) + C_1 + (B_2 + C_2 + B_2)$ (7 layers in the stack, $R_2$ order). Applying the same approach one can see that the stack $R_3$ consists of 15 alternating layers. In general the rule to construct of the fragments $B$, $C$ of stack can be written as

$$B_i \rightarrow B_{i+1} + C_{i+1} + B_{i+1}, \quad C_i \rightarrow C_{i+1}.$$ (1)

In standard Cantor set the central fragment $C$ is removed in the iterations that leads to a Cantor “dust” fractal [14]. However in this paper we replace $C$ (rather than delete) fragment by SiO$_2$ layer, while $B$ fragment is replaced by Si layer. This allows constructing a solid spherical quasiperiodic stack with the generic properties of a Cantor fractal pattern. For such fractal the dimensionless scaling factor $\gamma$ becomes a control parameter that takes values between 0 and 2. Although such Cantor stack has the alternating structure $BC, \ldots, CB, \ldots$, but due to no-symmetric generation rule (1) it is not longer periodic composition rather than a sequence of nonperiodic defects. Such stack looks like a pattern with progressive decreasing spatial scales (see Fig. 1) that leads to formation of extremely narrow transmittance resonances in the frequency domain due to the field phase interferences in such a structure.

3. BASIC EQUATIONS

To study the spectra of such system we solve the Maxwell equations for fields $E$, $B$ and the dielectric permittivity $\varepsilon$ of a layer. The Maxwell equations in the spherical coordinate frame $(\rho, \theta, \varphi)$ usually is reduced to the Helmholtz equation for a Debye potential $\Pi(\rho, \theta, \varphi)$ [17]. To avoid needless repetitions, the case of TM waves is investigated here with details, the case of TE waves can be studied by similar way. The solution for $E$ and $H$ fields in terms of the Debye potential $\Pi(\rho, \theta, \varphi)$ is given by

$$E_\theta = \frac{1}{kr\varepsilon} \frac{\partial^2 \Pi(\rho, \theta, \varphi)}{\partial \rho \partial \theta}, \quad H_\varphi = \frac{i}{r} \frac{\partial \Pi(\rho, \theta, \varphi)}{\partial \theta} \sqrt{\frac{\varepsilon_0}{\mu_0}}.$$ (2)

In every layer of the stack, one uses the next matrix presentation for the fields: (see e.g., Ref. [16] and references therein)

$$\vec{u} = \begin{bmatrix} H_\varphi \\ E_\theta \end{bmatrix} = \hat{D} \cdot \begin{bmatrix} a \\ b \end{bmatrix} = \hat{D} \cdot \vec{q},$$ (3)
where \( a \) and \( b \) are arbitrary constants and matrix \( \hat{D} = \hat{D}(y) \) is given by (see more details in Ref. [16]):

\[
\hat{D} = \begin{bmatrix}
  inP^{(2)}_m(y)e^{iy} & inP^{(1)}_m(y)e^{-iy} \\
  G^{(2)}_m(y)e^{iy} & G^{(1)}_m(y)e^{-iy}
\end{bmatrix}, \quad \vec{q} = \begin{bmatrix} a \\ b \end{bmatrix},
\]

Here \( n \) is the refractive index of a particular layer, \( P^{(1,2)}_m(y) \) the rational part of Hankel spherical functions \( h^{(1,2)}_m(y) = P^{(1,2)}_m(y)e^{\pm iy} \), and \( G^{(1,2)}_m(y) \) the rational part of a derivative of Hankel spherical functions \( (\partial/\partial y)h^{(1,2)}_m(y) = G^{(1,2)}_m(y)e^{\pm iy} \), and \( m \) the number of a spherical harmonic, \( y = \omega nr/c \). This allows presentation of the reflection coefficient \( R = R(\omega) \) and transmission coefficient \( T = T(\omega) \) in the following form \( (\sigma = (n_0/n_N)^{1/2}) \) [16]

\[
R = R(\omega) = \frac{Q_{21}(\omega)}{Q_{11}(\omega)}, \quad T = T(\omega) = \frac{1}{\sigma Q_{11}(\omega)},
\]

where matrix \( Q_{ij}(\omega) \) depends on \( P_m, G_m \) and is written in [16]. In (4) two equations relate three variables: \( R, T \) and frequency \( \omega \). Defining \( \omega \), one can calculate the frequency dependence of \( R(\omega), T(\omega) \) for the spherical stack. It is worth to note that both the reflection coefficient \( R \) and the transmittance coefficient \( T \) depend also on the number of a spherical harmonic \( m \). Below we give more attention to the dynamics of the transmittance coefficient \( T \). The eigenfrequencies equation for a coated microsphere follows from the boundedness of fields in the microsphere center and it has a simple form \( R(\omega) = 1 \) [16].

4. NUMERICS

Our results are shown in Figs. 2–5. As it was already mentioned such a Cantor set has the alternating structure \( ABCB, \ldots, CB, \ldots, D \) that due to non-symmetric rule Eq. (1) generates the sequence of (nonperiodic) defects. Such a stack with diminishing spatial scales can form very narrow electromagnetic transmittance resonances due to quasiperiodic phase interplay of photons. Due to radial dependence of the electromagnetic fields (in general we have to use Hankel functions rather than sine and cosine) it is very difficult to analyze the frequency spectrum of such Cantor stack analytically. Therefore in what follows the numerical methods will be used.

\[\text{Figure 2. Transmittance spectra for the spherical Cantor stack with different order } R_l \text{ for the frequency range } f \text{ from 100 [THz] to 600 for } \gamma = 1. \text{ In panels are shown cases } (a) l = 1, (b) l = 2, (c) l = 3, \text{ and } (d) l = 4. \text{ See details in text.}\]
First we consider the structure of the frequency spectrum of the transmittance at change of the number of layers (order Cantor subset $R_l$) of the stack. The case $m = 1$ is studied with more details. We consider that on each step $l$ a Cantor sequence is created by splitting Si layer into three fragments from which the central one is replaced by SiO$_2$ material. In the first case the system consists of three layers (that is $R_1$ order), in the second case the system consists of 7 layers (order $R_2$). In the third and fourth cases the system consists of 15 and 31 layers respectively ($R_3$ and $R_4$ orders). Further we study the practically important interval of frequency $f = \omega/2\pi$ from 100 [THz] to 600 [THz].

Figure 2 shows the structure of the frequency spectrum for different $R_l$ for the simplest case $\gamma = 1$ (standard Cantor configuration). Fig. 2(a) shows that for $R_1$ order (three layers in the stack) the spectrum has a simple periodic structure. However already for $R_2$ stack the spectrum becomes more complicate (see Fig. 2(b)) and narrow resonances of high transmittance are generated. Further the order increasing to $R_3$ (Fig. 2(c)) leads to the extremely narrower resonances. Then for $R_4$ stack, as Fig. 2(d) shows, the spectrum acquires the irregular shape.

It is instructive to explore the general case of the control parameter $\gamma$ to see how the value of $\gamma$ affects the structure of the transmittance spectrum in the considered Cantor multilayered microsphere. Such dependencies of transmittance $T$ as a function of $\gamma$ for $R_3$ stack are displayed in Fig. 3 for $\gamma < 1$ and in Fig. 4 for $1 < \gamma < 2$. One can see from Fig. 3 that the narrow resonances are formed by splitting the edges of the transmittance wide zones already at $\gamma = 0.5$. From Fig. 3 we also observe that the periodicity in the spectrum practically disappears already for $\gamma = 0.2$.

Figure 4 shows that the behavior of the transmittance spectra for case $\gamma > 1$ differs significantly from case $\gamma < 1$ for the same frequency range displayed in Fig. 3. From Fig. 4, we observe a significant shrinking of the high transmittance area in low frequency range.

**Figure 3.** Transmittance spectra for the frequency range $f$ from 100 to 600 [THz] for different width parameter $\gamma < 1$ from 0.1 up to 0.9 for SiO$_2$ layer for spherical stack with a Cantor structure.

**Figure 4.** The same as in Fig. 3 but for $1 < \gamma < 2$.

Besides, from Fig. 4 one can observe the appearance of a self-similarity in some parts of the spectra. However, such an effect in spherical structure is not clearly seen due to the frequency dispersion in spherical systems [3]. Mathematically it is expressed by the replacement of the trigonometric functions (plane geometry) by the complex Hankel functions (spherical geometry).

Hereinbefore we have considered properties of narrow resonances in the frequency domain. It is of considerable interest to obtain the eigenfrequencies and corresponding spatially fields dependencies (eigenfunctions) in such a multilayered system. The boundedness of the field solution in the centre of a microsphere and the Sommerfeld radiation condition in the boundary of the spherical stack were imposed. In order to calculate the eigenfrequencies we solved numerically the above-written eigenfrequencies equation $R(\omega) = 1$. Corresponding radial distribution of the electromagnetic field
Figure 5. The radial field distribution corresponding to eigenfrequency resonances closely to peaks from Fig. 3. It is shown the cases: (a) $\gamma = 0.8$ at $f = 300$ [THz], (b) $\gamma = 1$ at $f = 304$ [THz], (c) $\gamma = 0.5$ at $f = 309$ [THz], and (d) $\gamma = 0.7$ at $f = 399$ [THz].

along the radius of spherical stack it is shown in Fig. 5 for the spherical number $m = 1$ (fundamental TM mode). In order to see more details of the fields in a Cantor stack it is also displayed the structure of the refraction index (arbitrary units) of layers. From Fig. 5, we observe that the fields are mainly concentrated in the microsphere, sharply (exponentially) decays in the area of the stack and practically does not leak into surrounding space. One can say that such Cantor spherical structure resonantly confines the field and practically does not allow it to be radiated from the coated microsphere. This can lead to very high values of the $Q$-factor for such excitations.

5. CONCLUSIONS

In this paper, we have numerically studied the electromagnetic properties (narrow peak positions) of the transmission spectra for microspheres coated by a multilayered stack with the generalized Cantor structure. As opposed to the standard Cantor system with removed $\gamma/3$ [$\gamma = 1$] section the generalized solid stack with alternating Si/SiO$_2$ layers (in place of empty Cantor section) for such fractal pattern with general values of $\gamma$ it is considered. It is found that the variations of $\gamma$ significantly affects the structure of the spectra. The waves phase interference in such a fractal pattern leads to creation of extremely narrow frequency peaks assisted by the progressively decreased radially inhomogeneous defects. Such peaks can be used in modern optoelectronics, e.g., for construction narrow optical filters.

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REFERENCES


